

# The All-FET Line Amp

This audio expert from Germany shares with us his latest design—this one an all-FET line amp. **By Erno Borbely**

In Parts 1 and 2 of my JFET articles in *Audio Electronics*<sup>1,2</sup>, I described the three basic circuits: common-source, common drain, and the differential amplifiers. Using these circuits you can build up all low-level circuitry in phono preamps, line amps, crossovers, mike preamps, mixers, and so on. In fact, quite a few readers ordered small quantities of the JFETs for experiments. I had the impression that most of them wanted to make some simple crossover circuits, but a couple also experimented with mike preamps.

Figure 1 shows the common-source amplifier from Fig. 7A in Part 1, with minor modifications. Because I intend to use 24V supplies in this series, I have redrawn the amp with this in mind. In order to have maximum voltage swing at the output, I changed the drain resistor to 5k62. The source resistor has been increased to 100R, to produce 2mA drain current with the particular JFET used ( $I_{DSS}$ : 7–8mA). The drain is sitting at approximately 12V DC.

This simple amp has a gain of 33 times; i.e., 30dB. The frequency response is 300kHz! The distortion is dominated by second harmonics, which is to be expected from a square-law device. At 1V RMS I measured 0.4% and at 3V RMS it increased to just over 1%. The linearity can be improved by increasing the supply voltage, as we have seen in Part 1<sup>1</sup>.

This very simple amp would probably make many SE fans happy. Unfortunately, the circuit is not complete, in that the output is at a DC voltage of 12V, and requires a capacitor to isolate it from the next amp in the chain. However, capacitor coupling—whether in tube or in FET

amps—always invites lots of discussion on the quality of the caps used (especially from those arm-chair amateurs who never build anything), so I always try to avoid them if possible!

Thanks to the availability of complementary devices in semiconductors (npn and pnp bipolars, and n-channel and p-channel FETs), it is easy to design DC-coupled circuits that do not use caps in the signal path. This article, therefore, focuses on DC-coupled amps.

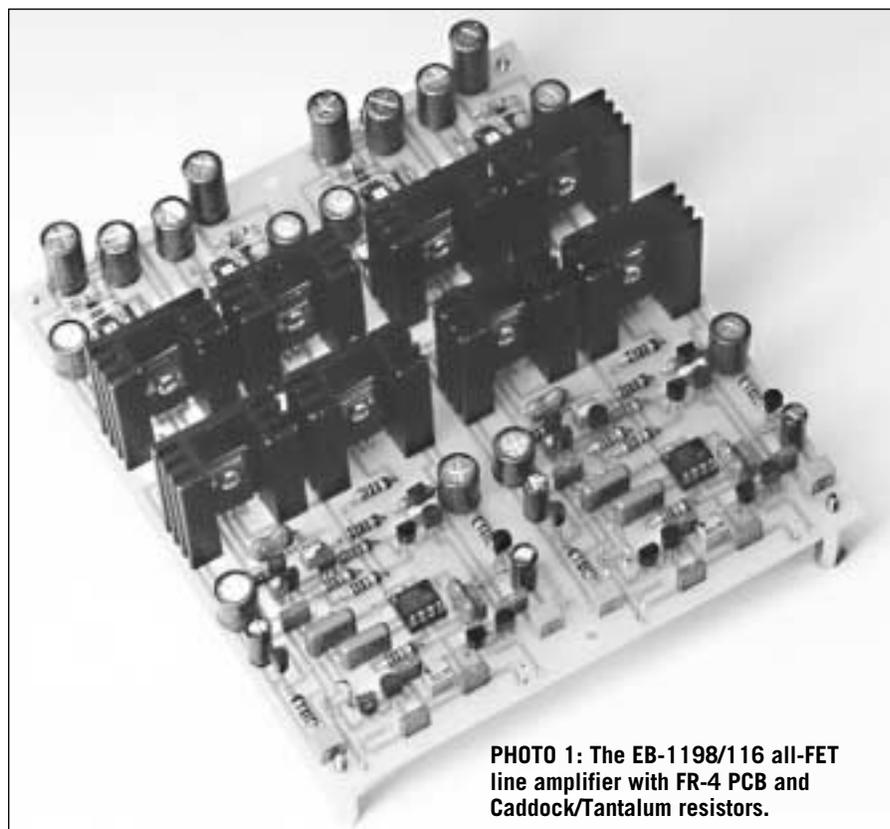
## THE TWO-STAGE SE AMP

Figure 2 shows a two-stage JFET amp, in which the second stage, also a com-

mon-source amplifier, level-shifts the DC of the first stage to 0V. The drain voltage of JFET 1 is no longer required to sit at half of the supply voltage, because it is not responsible for the output voltage swing. The voltage drop across the drain resistor should, in fact, be as small as possible, to allow the second stage to work at maximum drain/source voltage.

I usually work with about 3V, which is a compromise between enough voltage to turn on the second-stage JFET, and enough to produce a reasonable gain. I selected 10mA drain current in the second stage. A small trimpot is inserted in the source circuit of the second stage, which allows trimming the output to 0V. The second-stage JFET must be selected for  $I_{DSS} > 10\text{mA}$ , to avoid operating it with positive bias.

The open-loop gain (the feedback re-



**PHOTO 1:** The EB-1198/116 all-FET line amplifier with FR-4 PCB and Caddock/Tantalum resistors.

sistor  $R_F$  is open) is about 36dB and the frequency response is 150kHz. The reason for the relatively small increase of open-loop gain compared to the single-stage one is that we have reduced the gain in the first stage by using a smaller drain resistor, and the second stage also operates with a small(ish) gain because of the small drain resistor and the local feedback in the source. THD has been reduced a bit for the same output level, because of the higher available voltage swing in the second stage: 1V = 0.3%, 3V = 0.93%. Maximum output voltage before clipping is >10V RMS.

**TABLE 1  
THD MEASUREMENTS FOR  
AMPLIFIER SHOWN IN FIG. 4**

OUTPUT V RMS	RF = 1k (GAIN: 20.9dB)	
	1kHz THD	10kHz THD
1V	0.0015	0.0035
3V	0.0024	0.0075
5V	0.005	0.0145
6.5V	0.0075	0.02
8V	0.012	0.027
10V	0.029	0.044

I have indicated a feedback resistor  $R_F$  from output to the source of the first stage. However, applying a useful feedback is not easy, since the source resistor, setting the operating point in the first stage, is fixed at 100R. If you want to have, say, a closed-loop gain of 10x, you would need an  $R_F = 1k$ , which would load the second stage too much. Also, the open-loop gain of the amp is too low to have a useful amount of gain applied for feedback.

### OPEN-LOOP GAIN

You can increase the open-loop gain, and thereby the available gain for feedback, by increasing the gain in the second stage. The easiest way to do this is to replace the 2k43 resistor (which supplies 10mA) with a 10mA constant-current source, such as the E-103 (Fig. 3). The E-103 has a dynamic impedance of >100k and increases the open-loop gain by 20dB when the amp is loaded with a 10k resistor. Measurements show that this in itself does not improve the linear-

ity of the stage, but now you have more gain that you can apply as feedback.

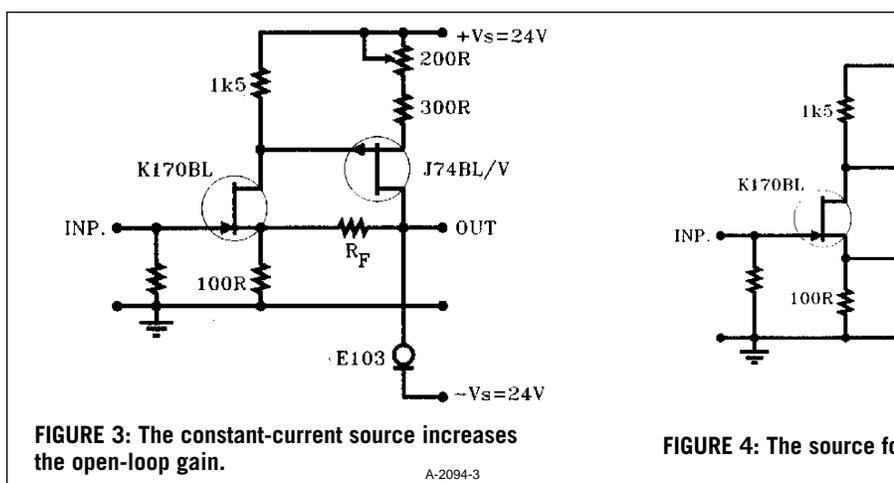
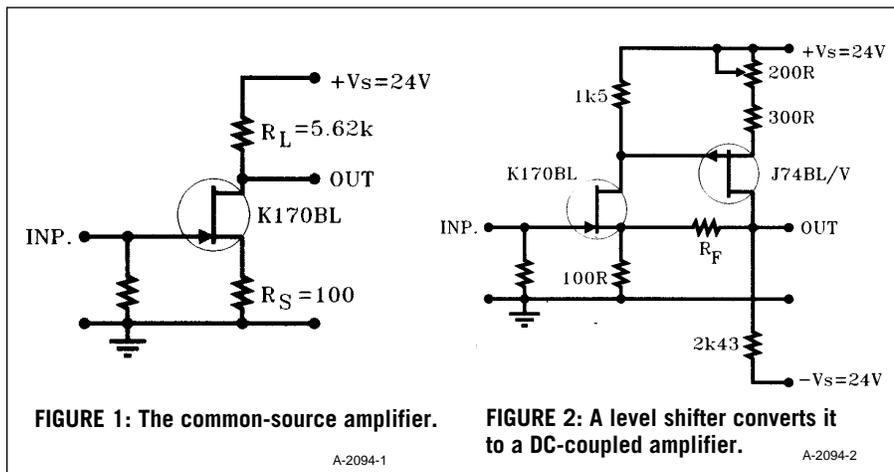
To address the load capability of the second stage, I have added a source follower to the amp (Fig. 4), described in Part 2<sup>2</sup> (Fig. 16B). The source follower adds a number of advantages to the amp: it isolates the feedback resistor from the high output impedance of the second stage, thereby further increasing the open-loop gain, and it provides a low output impedance to drive the feedback resistor and outside load. Closed-loop gain with  $R_F = 1k$  is 20.9dB. The closed-loop frequency response is more than 1MHz! Table 1 shows the THD measured on this amp. Overall a simple, but very good, SE line amp!

### THE COMPLEMENTARY GAME

Although this SE amp functions well, I have two issues with it. The first is its DC stability. As described in Part 1<sup>1</sup>, the transconductance curve of JFETs is temperature-dependent, and unless you operate it at zero tempco, you will have a temperature drift. Of course, a few mV of drift is acceptable in most audio applications; however, here we will try to minimize this as much as possible. Naturally, the open-loop linearity can also be improved. Enter the fully complementary circuitry.

Consider the circuit in Fig. 3 as half of such a complementary circuit. Imagine folding down this circuit along the horizontal ground line, naturally replacing the n-channel with p and vice versa. Figure 5 shows this basic 4-JFET configuration. The trimpot is used to adjust the output offset to 0V.

I have kept the same currents in both



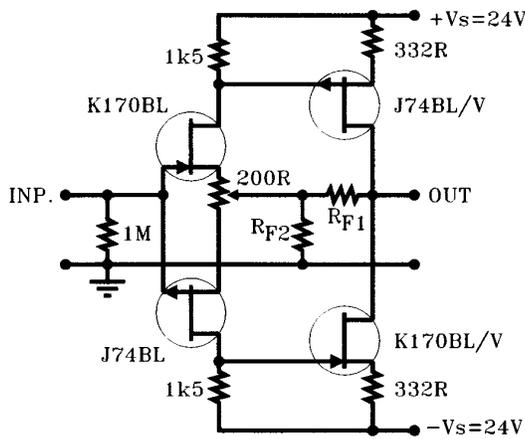


FIGURE 5: The basic 4-JFET complementary amp.

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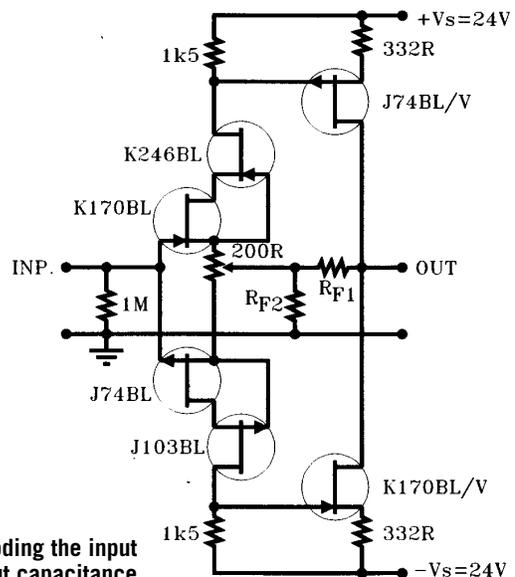


FIGURE 6: Cascoding the input reduces the input capacitance.

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input stage and second stage at 2mA and 10mA as before. Since the second stage consists of two JFETs connected together at their drains, they act as constant-current sources to each other. The amp therefore becomes a transconductance amplifier, converting input voltage to output current. The conversion back to voltage happens when you connect a resistor from the output to ground as a load resistor, or back to the negative input as a feedback resistor.

Here a feedback resistor is shown, representing the load at the output. The open-loop voltage gain is therefore very much dependent on this load resistor. I am usually using  $R_{F1} = 2k21$  feedback resistor; open-loop gain is equal to 42dB with this load. The open-loop frequency response is about 150kHz, same as the SE circuit.

Open-loop distortion is almost an order of magnitude less than for the SE circuit, indicating that the complementary circuit, depending on the matching of the JFETs used, is cancelling some of the second harmonic distortion. DC stability has also improved significantly due to the use of complementary devices cancelling the drift.

There are many more possibilities in terms of applying feedback than with the SE circuit, and you can produce a number of useful circuits. If you select  $R_{F1} = 2k21$  and  $R_{F2} = 221R$ , you will have a line amp with 20.9dB gain. You can also make  $R_{F2} = 2k21$  for a 6dB

**TABLE 2**  
**THD MEASUREMENTS FOR THE 4-JFET AMP SHOWN IN FIG. 5**

OUTPUT	OPEN-LOOP		10× GAIN (20dB)		2× GAIN (6dB)		UNITY GAIN*	
	1kHz	10kHz	1kHz	10kHz	1kHz	10kHz	1kHz	10kHz
	1V	0.032	0.033	0.0025	0.0047	0.0012	0.003	0.0011
3V	0.095	0.097	0.0055	0.015	0.0016	0.0058	0.0016	0.003
5V	0.165	0.17	0.0095	0.021	0.0032	0.012	0.0032	0.0068
6.5V	0.22	0.23	0.013	0.03	0.0048	0.016	0.0047	0.012
8V	0.28	0.3	0.018	0.04	0.007	0.022		
10V	0.37	0.4	0.028	0.06	0.0115	0.033		

\*Measurements limited by HP 339A output voltage.

**TABLE 3**  
**THD MEASUREMENTS FOR THE "SUPER BUFFER" SHOWN IN FIG. 8**

OUTPUT	OPEN-LOOP		10× GAIN (20dB)		2× GAIN (6dB)		UNITY GAIN*	
	1kHz	10kHz	1kHz	10kHz	1kHz	10kHz	1kHz	10kHz
	1V	Noise	Noise	0.0015	0.0025	0.0012	0.0021	0.0012
3V	0.025	0.05	0.0011	0.0015	0.0011	0.0015	0.0011	0.0015
5V	0.035	0.084	0.0011	0.0024	0.0011	0.0022	0.0011	0.0022
6.5V	0.05	0.11	0.0011	0.0026	0.0011	0.0022	0.0011	0.0022
8V	0.07	0.15	0.0011	0.0034	0.0011	0.0028		
10V**	0.12	0.4	0.0012	0.007	0.0012	0.0047		

\*Measurements limited by HP 339A output voltage.  
\*\*The amp starts clipping at 10V RMS.

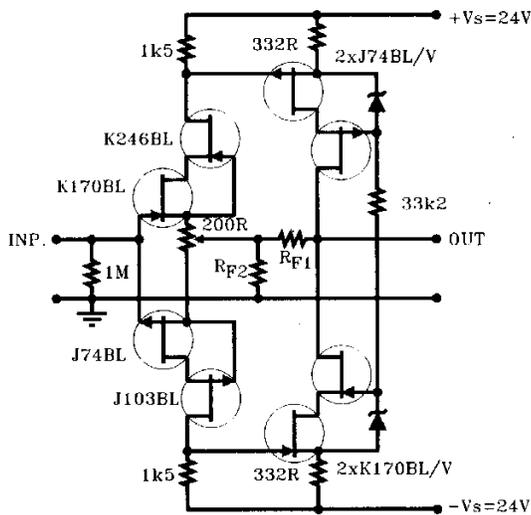
amp, which is very useful as a buffer between your CD player and your power amp, when you need a volume control in-between. If you remove  $R_{F2}$  completely, you will have a unity gain buffer. Table 2 shows the THD for this buffer with different gain settings.

### REDUCING THE INPUT CAPACITANCE BY CASCODING

The input capacitance of the basic 4-JFET circuit in Fig. 5 is about 28pF.

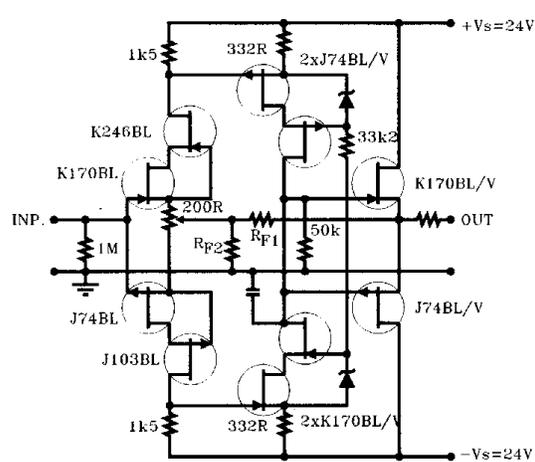
This is normally no problem when the source impedance is lower than 10k. However, the input capacitance of the JFETs is voltage dependent, and when driven from high impedance it might cause distortion.

You might recall that we solved this problem in Part 1 by cascoding the input JFET with another one (Fig. 9A/B in Part 1). This circuit is shown in Fig. 6. The cascoding reduces the input capacitance to less than 2pF, and there is



**FIGURE 7: Cascoding the second stage improves the high-frequency linearity.**

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**FIGURE 8: The "Super Buffer."**

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no sign of any distortion with high source impedances.

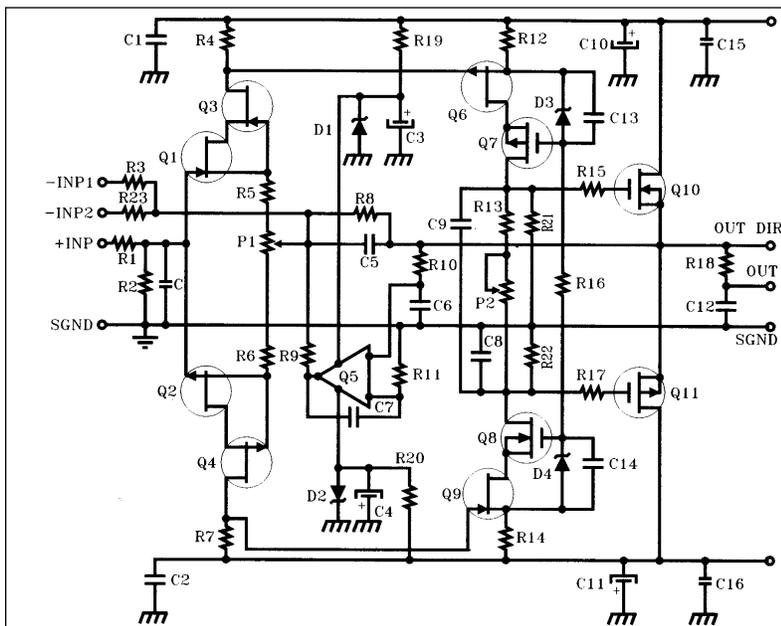
Cascoding the second stage as well (Fig. 7) can make further improvements. This helps reduce the internal capacitances and capacitance modulation. However, all these circuits have a high output impedance and because the open-loop gain is limited, even the feedback cannot reduce it to very low levels.

Of course, this is not an important factor in normal line amp applications; however, when used as a unity gain buffer in filter applications, it is essential. I have therefore added a complementary source follower to the output. Figure 8 shows the final all-JFET "Super Buffer."

Since there is no load on the second stage, the open-loop gain is very high. In fact, it is too high for my liking, and I usually reduce it with a resistive load on the second stage. With 50k the open-loop gain is 67dB. Open-loop frequency response is close to 20kHz.

The THD for four different gain settings is shown in Table 3. Note the very low open-loop distortion indicating very good linearity. Due to the voltage drop across the bias circuit in the second-stage cascode, the amp starts to clip just around 10V RMS. This is responsible for the slightly increasing THD levels at 10V. A higher supply voltage would allow more output without clipping.

The amp needs a series resistor at the output (47Ω) for stability. The actual output impedance of the amp is about



**FIGURE 9: The EB-1198/116 all-FET line amp.**

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2Ω, and with the series resistor it's 50Ω. The amp can drive loads down to 1kΩ, with no increase in THD. The frequency response with 10× gain is more than 1MHz! In unity gain it has a rise time of <100ns, indicating a frequency response well into the MHz region.

The circuit also shows very good noise performance. Measured in the 10× gain position with 2k21/221R feedback resistors, the input noise is <0.4μV over the audio bandwidth. You can further reduce the input noise by paralleling several input stages. See the input stage of the all-FET phono preamp on my homepage (www.borbelyaudio.com).

### THE ALL-FET LINE AMP (EB-1198/116)

I have used the amp shown in Fig. 8 in many line amp and filter applications with very good results. It's simple, inexpensive, and has an extremely high resolution. However, for a commercial product I wanted even higher drive capability.

My goal was to be able to drive loads down to about 100Ω in pure Class-A, also allowing it to be used as a headphone amp. To be able to drive 100Ω in Class-A with up to 10V RMS, you need to have a bias current of 70mA. There are no JFETs that can withstand this power

dissipation, and I used MOSFETs as output devices. The schematic of the all-FET line amp is shown in Fig. 9.

The input JFET-cascode, consisting of Q1-Q2-Q3 and Q4, is operated at 2mA, and Q1 and Q2 must be matched to  $\pm 10\%$  of  $I_{DSS}$ . Q1 and Q2 are selected from the "BL" group, and, depending on  $I_{DSS}$ , they are adjusted for  $I_D = 2mA$  by R5 and R6. (For selection of JFETs see the test jig described in Part 1.) Q3 and Q4 must have a gate-source voltage of minimum 2V at this current, to provide proper drain-source voltage to Q1-Q2.

The second stage, consisting of JFETs Q6-Q9 and MOSFETs Q7-Q8, operates at just below 10mA. Select Q6 and Q9, which must be matched to each other, for  $I_{DSS} > 10mA$ . It is easiest to select these from the "V" group, because the minimum  $I_{DSS}$  for this group is 10mA ( $I_{DSS}$ : 10-20mA). I am using MOSFETs as cascode devices because I wanted to try the circuit with higher supply voltages than the JFETs would allow. The output devices, Q10-Q11 (Hitachi TO-220 MOSFETs), are operating at approximately 70mA; proper heatsinking is therefore mandatory.

Although the DC stability of the amp is very good, I added a servo to ensure very low offset voltage, independent of the ambient temperature. Q5 is a JFET-input servo amplifier, providing tracking of the output offset to less than a couple of mV. The RC networks of R10-C6 and R11-C7 filter out all AC signals over 1Hz. The servo is therefore only operational under 1Hz, and should not affect the sound of the amplifier. Nevertheless, if you believe that it does, don't hesitate to try different op amps for this. D1 and D2 are IC shunt regulators, supplying Q5 with  $\pm 10V$ .

For an all-out line amp, the best resistors are the Vishay S102s and the Caddock MK132s. Personally, I prefer the Caddocks, which seem to be more neutral than the Vishays. However, you don't need to use all-Vishays or all-Caddocks to get super sound; only the input and feedback resistors (R1, R2, R3, R4, R7, and R8) should be from these. The rest could be Tantalum (I have found these give the best combination with the Caddocks), but DALE RN60s are also good (but only the ones

using non-magnetic construction). The frequency compensating capacitors are polystyrene or Mica caps, the electrolytics C10 and C11 are ELNA CERAFINE, and the rest of the caps are WIMA and Roederstein.

The open-loop gain of the amplifier is kept at a relatively low 66dB by the two resistors R21-R22. Open-loop frequency response is 20kHz (-3dB)! Open-loop THD is very low: 0.055% at 1kHz, 3V RMS and 0.095% at 10kHz, 3V RMS. This is reduced to below the measurement limit of the HP 339A distortion analyzer when feedback is applied with resistors R8-R3.

Normally, R8 is 2k and R3 is 221 $\Omega$ . This gives a closed-loop gain of 20dB. Changing the ratio of R8-R3 can reduce the closed-loop gain. The rise time of the amplifier is less than 200ns for an output of +10V. Closed-loop frequency response is over 1MHz! Output impedance is less than 10 $\Omega$  at the "direct" output and is approximately equal to R18 at the "normal" output.

The all-FET line amp also has low-noise, wideband regulators on the PCB (schematic not shown here). These are using low-noise JFET-input op amp and MOSFET outputs. The power-supply requirement is  $\pm 29V$  unregulated voltage at 100mA per channel. A high-quality power supply with fast/soft recovery diodes and high-quality 10,000-22,000 $\mu F$  electrolytics is recommended. Two of the line amps can also be connected for balanced operation.

## TESTIMONIALS

Finally, here are a couple examples of authentic customer feedback from the US and Canada:

"After living with the line amp for quite a few weeks now, I would say the following is what I hear:

- incredible resolution in loud, congested orchestral passages; e.g., locating triangles on top of full orchestra
- amazing sense of "air," space, width, depth; i.e., imaging is holographic
- startling resolution in what I call "leading edge transients" on, for example, brass, drums, and so forth.

I could go on and on, but, you'll think I'm hyperbolizing! I can't imagine improving on your design."

"It (the all-FET line amp) has extraordinary detail, very accurate harmonic structure, powerful macro and micro dynamics, and an extremely low noise floor allowing effortless transient attack, and vocal intonation and ambient decay to be vividly portrayed...." ❖

## PARTS LIST FOR EB-1198/116

R1	100R Caddock MK132
R2	100k Caddock MK132
R3	221R Caddock MK132
R4, R7	1k5
R5, R6	Adj. for 2mA drain current
R8, R23	2k21 Caddock MK132
R9, R21, R22	100k
R10, R11	1M
R12, R14	330R
R13, R15, R17	100R
R16	33k
R18	47R
R19, R20	1k ROE WK2 1.1W
P1	200R COPAL RJ5W
P2	500R COPAL RJ5W
C, C5	10pF/500V PS, MICA
C1, C2	0.1 $\mu F$ /100V ROE MKT-1826
C3, C4	100 $\mu F$ /25V ROE EKO
C6, C7	0.22 $\mu F$ /160V WIMA MKP4
C8	150pF/500V PS, MICA
C9, C13, C14, C15, C16	0.1 $\mu F$ /100V ROE MKT 1826
C10, C11	47 $\mu F$ /35V ELNA CERAFINE
C12	560pF/500V PS, MICA
Q1	K170BL Matched to Q2
Q2	J74BL Matched to Q1
Q3	K246BL
Q4	J103BL
Q5	AD820AN Analog Devices
Q6	J74V Matched to Q9
Q7	J148
Q8	K982
Q9	K170V Matched to Q6
Q10	K216
Q11	J79
D1, D2	LM4040DIZ
D3, D4	LM336Z-5.0

### MISCELLANEOUS

PCB: EB-1198/116/BUFFER45

Heatsinks Fischer SK75 37.5mm

Note: Resistors are Tantalum or Vishay-Dale, unless otherwise noted.

The EB-1198/116 kit, including power supply, volume control, connectors, and case is available from:

Borbely Audio

Angerstr. 9

86836 Obermeitingen, Germany

+49/8232/903616

Fax: +49/8232/903618

Web: www.borbelyaudio.com

## ACKNOWLEDGMENT

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## REFERENCES

1. Erno Borbely, "JFETs: The New Frontier, Part 1," AE 5/99.
2. Erno Borbely, "JFETs: The New Frontier, Part 2," AE 6/99.